

MOS FIELD EFFECT TRANSISTOR

NP40N055CHE,NP40N055DHE,NP40N055EHE,NP40N055KHE

ORDERING INFORMATION

PART NUMBER

NP40N055CHE

NP40N055DHE

NP40N055EHE

NP40N055KHE

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

These products are N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance
- $R_{DS(on)} = 23 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 20 \text{ A})$
- Low Ciss : Ciss = 1070 pF TYP.
- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage	VDSS	55	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	D(DC)	±40	А
Drain Current (Pulse) Note1	D(pulse)	±100	А
Total Power Dissipation ($T_A = 25^{\circ}C$)	P⊤	1.8	W
Total Power Dissipation (Tc = 25°C)	Pτ	66	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Current Note2	las	29 / 21 / 7	А
Single Avalanche Energy Note2	Eas	0.8 / 44 / 49	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting T_{ch} = 25°C, V_{DD} = 28 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V (See Figure 4.)

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	2.27	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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PACKAGE

TO-220AB

TO-262

TO-263 (MP-25ZJ)

TO-263 (MP-25ZK)

(TO-220AB)

ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, Id = 20 A		18	23	mΩ
Gate to Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2.0	3.0	4.0	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 20 A	7	14		s
Drain Leakage Current	loss	Vds = 55 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 25 V		1070	1610	pF
Output Capacitance	Coss	Vgs = 0 V		190	280	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		95	180	pF
Turn-on Delay Time	t d(on)	ID = 20 A		16	35	ns
Rise Time	tr	V _{GS} = 10 V		9.2	23	ns
Turn-off Delay Time	td(off)	Vpd = 28 V		29	57	ns
Fall Time	tr	$R_G = 1 \Omega$		9.2	23	ns
Total Gate Charge	Q _G	ID = 40 A		23	35	nC
Gate to Source Charge	QGS	$V_{DD} = 44 V$		6		nC
Gate to Drain Charge	Qgd	V _{GS} = 10 V		9		nC
Body Diode Forward Voltage	VF(S-D)	IF = 40 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 40 A, VGS = 0 V		38		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μ s		46		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY





TEST CIRCUIT 3 GATE CHARGE



TEST CIRCUIT 2 SWITCHING TIME

+





TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)







Figure6. FORWARD TRANSFER CHARACTERISTICS









Figure9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

















I_F - Drain Current - A



Figure15. SWITCHING CHARACTERISTICS



Figure17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS



PACKAGE DRAWINGS (Unit: mm)

1) TO-220AB (MP-25)





3) TO-263 (MP-25ZJ)







EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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